

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231, on 8-8-94

- 1 -

Docket: 0756-958

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of )  
Shunpei YAMAZAKI et al. )  
Serial No. 08/183,800 ) Art Unit: 2508  
Filed: January 21, 1994 ) Examiner: M. Saadat  
For: SEMICONDUCTOR MATERIAL )  
AND METHOD FOR FORMING )  
THE SAME AND THIN FILM )  
TRANSISTOR ) Date: August 8, 1994



AMENDMENT

Honorable Commissioner of Patents and Trademarks  
Washington, D.C. 20231

Sir:

In response to the Office Action of April 8, 1994, please amend the subject application as follows:

IN THE CLAIMS:

Please amend claims 23, 25, and 27 as follows:

23. (Amended) A thin film transistor comprising:  
a channel semiconductor layer [comprising]:  
a gate insulating layer contacting said channel layer; and  
a gate electrode adjacent to said channel layer with said gate

*Albach*  
*#17/10*  
*Am*

*8/25/94*

*Long*  
*EV*  
*D*